

SANYO Semiconductors DATA SHEET

N-Channel Silicon Junction FET

CPH6901— Low-Frequency General-Purpose Amplifier, **Differential Amplifier, Analog Switch Applications**

Features

- · Composite type with 2 FET contained in a CP package currently in use, improving the mounting efficiency greatly.
- The CPH6901 is formed with two chips, being equivalent to the 2SK303, placed in one package.
- · Optimal for differential amplification due to excellent thermal equilibrium and pair capability.

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|------------|-------------|------|
| Drain-to-Source Voltage | V _{DSX} | | 30 | V |
| Gate-to-Drain Voltage | V _{GDS} | | -30 | V |
| Gate Voltage | IG | | 10 | mA |
| Drain Current | ID | | 10 | mA |
| Allowable Power Dissipation | PD | 1 unit | 200 | mW |
| Total Power Dissipation | PT | | 300 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------------------|--|---------|------|-------|-------|
| Falanetei | | | min | typ | max | Offic |
| Gate-to-Drain Breakdown Voltage | V(BR)GDS | I _G =-10μA, V _{DS} =0 | -30 | | | V |
| Gate-to-Source Leakage Current | IGSS | V _{GS} =-20V, V _{DS} =0 | | | -1.0 | nA |
| Cutoff Voltage | VGS(off) | V _{DS} =10V, I _D =1μA | -0.3 | -0.8 | -1.25 | V |
| Gate-to-Source Voltage Difference | ΔVGS | VGS Large-VGS Small VDS=10V, ID=1mA | | | 50 | mV |
| Drain Current | IDSS | V _{DS} =10V, V _{GS} =0(FET1) | 1.2 | | 3.0 | mA |
| Drain Current Ratio | | IDSS Small / IDSS Large | 0.9 | | | |
| Forward Transfer Admittance | yfs | V _{DS} =10V, V _{GS} =0, f=1MHz | 3.0 | 4.5 | | mS |
| Forward Transfer Admittance Ratio | | yfs Small / yfs / Large | 0.9 | | | |
| Input Capacitance | Ciss | VDS=10V, VGS=0, f=1MHz | | 5.0 | | pF |
| Reverse Transfer Capacitance | Crss | VDS=10V, VGS=0, f=1MHz | | 0.9 | | pF |
| Static Drain-to-Source On-State Resistance | R _{DS} (on) | V _{DS} =10mV, V _{GS} =0 | | 250 | | Ω |

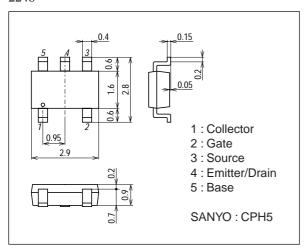
The specifications shown above are for each individual transistor.

Marking: 1G

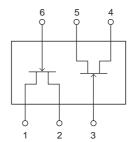
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Package Dimensions

unit: mm 2248

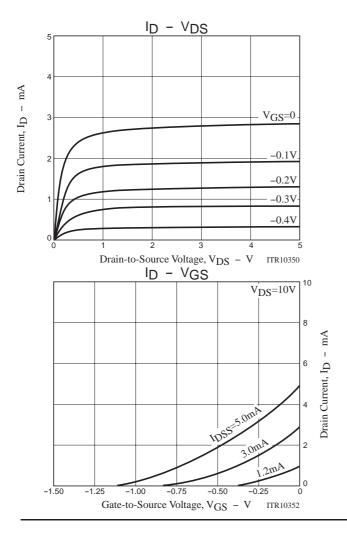


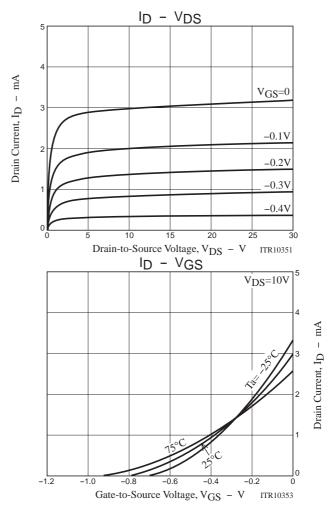
Electrical Connection

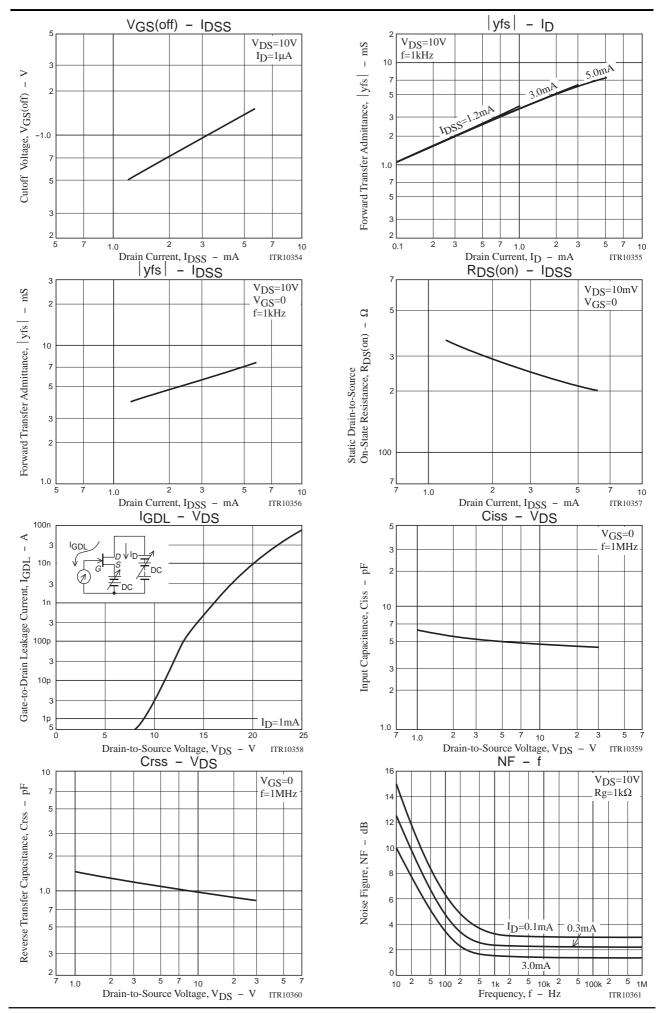


1 : Drain1 2 : Source1 3 : Gate2 4 : Source2 5 : Drain2 6 : Gate1

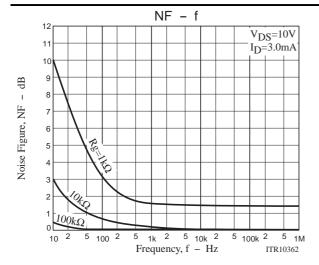
Top view

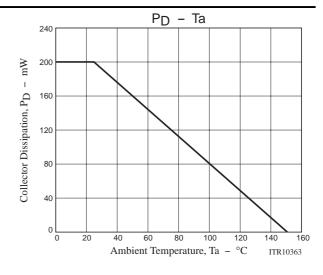






CPH6901





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